

v00.1113



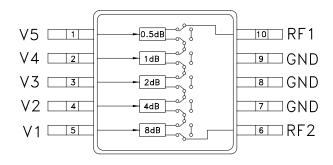
0.5 DB LSB GAAS MMIC 5-BIT DIGITAL ATTENUATOR, 0.7 - 3.8 GHz

Typical Applications

The HMC306AMS10 / 306AMS10E is ideal for:

- Cellular; UMTS/3G Infrastructure
- ISM, MMDS, WLAN, WIMAX
- Microwave Radio & VSAT
- Test Equipment and Sensors

Functional Diagram



Features

RoHS-Compliant Product 0.5 dB LSB Steps to 15.5 dB Single Positive Control Per Bit

± 0.2 dB Typical Bit Error

Miniature 15 mm² Package: MSOP10

General Description

The HMC306AMS10 & HMC306AMS10E are general purpose broadband 5-bit positive control GaAs IC digital attenuators in 10 lead MSOP surface mount plastic packages. Covering 0.7 to 3.8 GHz, the insertion loss is typically less than 1.5 to 2.3 dB. These attenuators' bit values are 0.5 (LSB), 1, 2, 4 and 8 dB for a total attenuation of 15.5 dB. Attenuation accuracy is excellent at \pm 0.2 dB typical with an IIP3 of up to +52 dBm. Five bit control voltage inputs, toggled between 0 and +3 to +5V, are used to select each attenuation state. A single Vdd bias of +3 to +5V applied through an external 5K Ohm resistor is required.

Electrical Specifications,

 $T_A = +25^{\circ}$ C, Vdd= +3V to +5V & VCTL= 0/Vdd (Unless Otherwise Stated)

Parameter		Frequency (GHz)	Min.	Typical	Max.	Units
Insertion Loss		0.7 - 1.4 1.4 - 2.3 2.3 - 2.7 2.7 - 3.8		1.3 1.5 1.8 2.3	1.6 2.0 2.5 2.7	dB dB dB dB
Attenuation Range				15.5		dB
Return Loss (RF1 & RF2, All Atten. States)		0.7 - 1.4 1.4 - 2.3 2.3 - 2.7 2.7 - 3.8	15 14 13 10	21 18 16 13		dB dB dB dB
Attenuation Accuracy: (Referenced to Insertion Loss) All Attenuation States 0.5 - 7.5 dB States 8.0 - 15.5 dB States All Attenuation States		0.7 - 1.4 1.4 - 2.3 1.4 - 2.3 2.3 - 3.8	± (0.25 + 5 ± (0.15 + 5	0 + 5% of Atten. Setting) Max. 5 + 3% of Atten. Setting) Max. 5 + 3% of Atten. Setting) Max. 0 + 3% of Atten. Setting) Max.		dB dB dB dB
Input Power for 0.1 dB Compression	Vdd = 5V Vdd = 3V	0.7 - 3.8		28 27		dBm dBm
Input Third Order Intercept Point (Two-tone Input Power = 10 dBm Each Tone)	Vdd = 5V Vdd = 3V	0.7 - 3.8		52 48		dBm dBm
Switching Characteristics						
tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)		0.7 - 3.8		560 600		ns ns

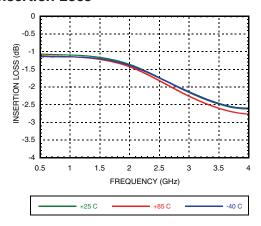


v00.1113



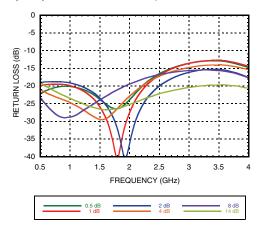
0.5 DB LSB GAAS MMIC 5-BIT DIGITAL ATTENUATOR, 0.7 - 3.8 GHz

Insertion Loss



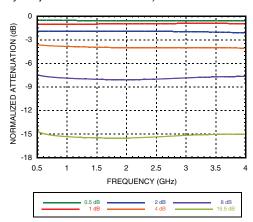
Return Loss RF1, RF2

(Only Major States are Shown)

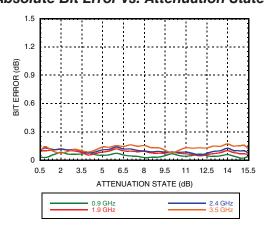


Normalized Attenuation

(Only Major States are Shown)

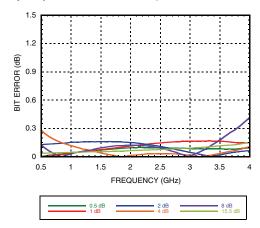


Absolute Bit Error vs. Attenuation State



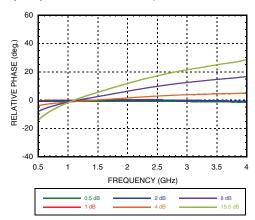
Absolute Bit Error vs. Frequency

(Only Major States are Shown)



Relative Phase vs. Frequency

(Only Major States are Shown)





v00.1113



0.5 DB LSB GAAS MMIC 5-BIT DIGITAL ATTENUATOR, 0.7 - 3.8 GHz

Truth Table

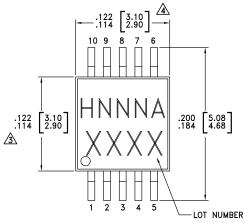
	Cont	rol Voltag	Attenuation		
V1 8 dB	V2 4 dB	V3 2 dB	V4 1 dB	V5 0.5 dB	State RF1 - RF2
High	High	High	High	High	Reference I.L.
High	High	High	High	Low	0.5 dB
High	High	High	Low	High	1 dB
High	High	Low	High	High	2 dB
High	Low	High	High	High	4 dB
Low	High	High	High	High	8 dB
Low	Low	Low	Low	Low	15.5 dB Max. Atten.

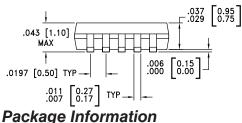
Any combination of the above states will provide an attenuation approximately equal to the sum of the bits selected.



ELECTROSTATIC SENSITIVE DEVICE **OBSERVE HANDLING PRECAUTIONS**

Outline Drawing





	•	_	•	-	J	LOT	NUMBER
.043 [1.10] (.037	[0.95] 0.75]
.0197 [0.50] TYP—	Ī	_			.006	0.15	

Control & Bias Voltages

State	Bias Condition		
Low	0 to +0.2V @ 20 μA Max.		
High	Vdd ± 0.2V @ 20 μA Max.		
Note: $Vdd = +3V \text{ to } 5V \pm 0.2V$			

Absolute Maximum Ratings

Control Voltage (V1 - V5)	Vdd + 0.2 Vdc	
Bias Voltage (Vdd)	+8 Vdc	
Channel Temperature	150 °C	
Continuous Pdiss (T = 85 °C) (derate 7.8 mW/ °C above 85 °C)	0.506 W	
Thermal Resistance (Channel to package bottom)	128.5 °C/w	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-40 to +85 °C	
RF Input Power (0.7 - 3.8 GHz)	+27 dBm	
ESD Sensitivity (HBM)	Class 1A	

NOTES:

.031 [0.80] .016 [0.40]

 $-.009 \ \begin{bmatrix} 0.22 \ 0.08 \end{bmatrix}$

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- DIMENSIONS ARE IN INCHES [MILLIMETERS].
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
 - ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

Part Number Package Body Material		Lead Finish	MSL Rating	Package Marking [3]
HMC306AMS10 Low Stress Injection Molded Plastic		Sn/Pb Solder	MSL1 [1]	H306A XXXX
HMC306AMS10E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	H306A XXXX

- [1] Max peak reflow temperature of 235 °C
- [2] Max peak reflow temperature of 260 °C
- [3] 4-Digit lot number XXXX



v00.1113

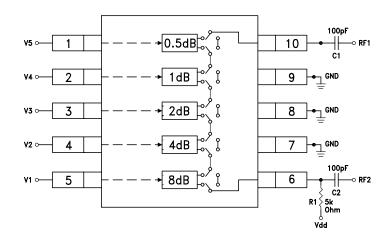


0.5 DB LSB GAAS MMIC 5-BIT DIGITAL ATTENUATOR, 0.7 - 3.8 GHz

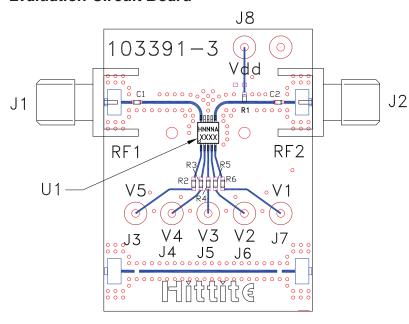
Application Circuit

Note:

DC Blocking Capacitors C1 & C2 are required on RF1 & RF2. Choose C1 = C2 = $100 \sim 300 \text{ pF}$ to allow lowest customer specific frequency to pass with minimal loss. R1= 5K Ohm is required to supply voltage to the circuit through either Pin 6 or Pin 10.



Evaluation Circuit Board



* R2 - R6= 100 Ohm. These resistors are optional and may be used to enhance decoupling of the RF path from the control inputs.

List of Materials for Evaluation PCB EVAL01 - HMC306AMS10 [1]

Item	Description
J1 - J2	PCB Mount SMA Connector
J3 - J8	DC Pin
R1	5 kOhm Resistor, 0402 Pkg.
R2 - R6	100 Ohm Resistor, 0402 Pkg.
C1 - C2	0402 Chip Capacitor, Select Value for Lowest Frequency
U1	HMC306AMS10 / 306AMS10E Digital Attenuators
PCB [2]	103391 Evaluation PCB 1.5" x 1.5"

[1] Reference this number when ordering complete evaluation PCB $\,$

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for RF Development Tools category:

Click to view products by Analog Devices manufacturer:

Other Similar products are found below:

MAAM-011117 MAAP-015036-DIEEV2 EV1HMC1113LP5 EV1HMC6146BLC5A EV1HMC637ALP5 EVAL-ADG919EBZ ADL5363EVALZ LMV228SDEVAL SKYA21001-EVB SMP1331-085-EVB EV1HMC618ALP3 EVAL01-HMC1041LC4 MAAL-011111-000SMB
MAAM-009633-001SMB MASW-000936-001SMB 107712-HMC369LP3 107780-HMC322ALP4 SP000416870 EV1HMC470ALP3
EV1HMC520ALC4 EV1HMC244AG16 MAX2614EVKIT# 124694-HMC742ALP5 SC20ASATEA-8GB-STD MAX2837EVKIT+
MAX2612EVKIT# MAX2692EVKIT# EV1HMC629ALP4E SKY12343-364LF-EVB 108703-HMC452QS16G EV1HMC863ALC4 119197HMC658LP2 EV1HMC647ALP6 ADL5725-EVALZ 106815-HMC441LM1 EV1HMC1018ALP4 UXN14M9PE MAX2016EVKIT
EV1HMC939ALP4 MAX2410EVKIT MAX2204EVKIT+ EV1HMC8073LP3D SIMSA868-DKL SIMSA868C-DKL SKY65806-636EK1
SKY68020-11EK1 SKY67159-396EK1 SKY66181-11-EK1 SKY65804-696EK1 SKY13396-397LF-EVB